JC09 Rec'd PCT/PTO 27 SEP 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

PIZZI Atty. Ref.: 4636-33

Serial No. **Unknown** Group:

National Phase of: PCT/IB2003/006283
International Filing Date: 23 December 2003

Filed: Herewith Examiner:

For: JUNCTION FOR PHOTOVOLTAIC CELLS, OPTICAL

SENSORS OR THE LIKE

September 27, 2005

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention of the Patent and Trademark Office the references listed on the attached form PTO/SB/08a. Copies of the non-U.S. references are enclosed. This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited.

The Examiner is requested to initial the attached form PTO/SB/08a and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

By:

Respectfully submitted,

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Form PTO FB A820 (Also PTO/SB/08A)

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